Optical properties, electron-phonon coupling, and Raman scattering of vanadium ladder compounds

J. Spitaler,^{1,*} E. Ya. Sherman,^{1,2} H. G. Evertz,² and C. Ambrosch-Draxl¹

¹Institut für Theoretische Physik, University Graz, Universitätsplatz 5, A-8010 Graz, Austria ²Institut für Theoretische Physik, Technical University Graz, Petersgasse 16, A-8010 Graz, Austria

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The electronic structure of two V-based ladder compounds, the quarter-filled NaV₂O₅ in the symmetric phase and the isostructural half-filled CaV₂O₅, is investigated by *ab initio* calculations. Based on the band structure we determine the dielectric tensor $\varepsilon(\omega)$ of these systems in a wide energy range. The frequencies and eigenvectors of the fully symmetric A_g phonon modes and the corresponding electron-phonon and spin-phonon coupling parameters are also calculated from first principles. We determine the Raman scattering intensities of the A_g phonon modes as a function of polarization and frequency of the exciting light. All results—i.e., shape and magnitude of the dielectric function, phonon frequencies, and Raman intensities—show very good agreement with available experimental data.

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I. INTRODUCTION

The vanadium-based ladder compounds NaV₂O₅ and CaV₂O₅ are interesting examples of systems where charge, spin, and lattice degrees of freedom are coupled to each other. Like materials with magnetically active Cu ions forming ladderlike structures,^{1,2} they show unusual physical properties due to a strong interaction of all degrees of freedom. The main building block of their unit cells is a ladder formed by V-O rungs and V-O legs, as is shown in Fig. 1. Both materials crystallize in the orthorhombic space group *Pmmn* (D_{2h}^{13}) with two formula units per unit cell.

Electrons in these systems can move within a rung, between rungs within a ladder, and between different ladders. The upper occupied electron states are formed by d_{xy} electrons of V with a slight admixture of oxygen 2p orbitals. In NaV_2O_5 , one d_{xy} electron of V is shared by two sites within a rung which leads to a quarter-filled character³ and makes this compound a dielectric, since the hopping of an electron between two rungs, which would produce a doubly occupied and an empty rung, requires more energy than can be provided by the hopping matrix element along the ladders. At a critical temperature T_c close to 35 K, NaV₂O₅ undergoes a transition to a spin-gapped state, as first reported by Isobe and Ueda in Ref. 4 based on the analysis of magnetic susceptibility measurements. Evidence for such a transition was also obtained in Raman scattering experiments.⁵ This behavior, in some aspects analogous to the spin-Peierls transition observed in the inorganic chain compound $CuGeO_3$ at T_{SP} =13.5 K⁶, is accompanied by a disproportion of the V charges $(4.5 \pm \delta)$, a relatively large lattice distortion, and the formation of an ordered charge pattern. At $T \ll T_c$ the ions are displaced from their equilibrium positions in the hightemperature phase by distances of the order of 0.05 Å. These displacements which give evidence for a strong electronlattice coupling have been observed in x-ray diffraction^{7–9} and can be estimated from infrared¹⁰ and Raman scattering experiments.¹¹ They stabilize the zigzag ordered phase,^{12,13} being probably the crucial element that determines the physics of the charge ordering in this compound. At the same time, the coupling to dynamical phonons induces strong charge fluctuations near T_c which alter the spin-spin exchange J.¹⁴ Also the ordering is not completely static, even at low temperatures, since it is influenced by lattice vibrations, as was found in electron spin-resonance experiments.¹⁵ At the same time, one could expect that charge ordering accompanied by a lattice distortion will show up, for example, in the dielectric function with decreasing temperature. However, a comparison of optical spectra taken at the low- and high-temperature phases, respectively, exhibits only small differences below T_{c} ¹⁶ while Raman spectra reveal large changes in the electronic background and show many new peaks which could have either magnetic or phononic origin when going below T_c .¹¹ New peaks are also clearly seen in the low-temperature infrared spectra.¹⁰ A full understanding of these new modes is still lacking.

In CaV₂O₅, each V ion has spin $\frac{1}{2}$ and it can therefore be described by a generalized Heisenberg model of the spinspin interaction. In this case, phonons directly influence the exchange constants and, therefore, lead to a modification of the magnetic properties. The spin gap in this compound, arising due to different exchange along the legs and along the rungs, is of the order of 500 K (0.05 eV).¹⁷ We mention that the Heisenberg spin-spin exchange parameters and, in turn, the strength of spin-phonon coupling depend on the electron on-site energies and the hopping matrix elements which form the band structure and influence the dielectric function. For this reason, experimental and theoretical investigation of the optical conductivity, the lattice dynamics, and the electronphonon and spin-phonon coupling can provide a clue to the properties of NaV₂O₅ and CaV₂O₅ and shed light on the origin of the phase transition in the former.

 NaV_2O_5 and CaV_2O_5 have been the subject of intensive theoretical investigations, both by first principles based on density functional theory (DFT) and by model calculations.^{18–23} In first-principles calculations, the tightbinding linear muffin-tin orbitals (LMTO) method^{24,25} in the atomic sphere approximation (ASA) and the linear combina-



FIG. 1. The crystal structure of NaV_2O_5 and CaV_2O_5 . (a) The view along the ladders, (b) the view from the top. The dashed lines correspond to relatively weak bonds between the ladders. X indicates either Na or Ca, respectively.

tion of atomic orbitals²⁶ (LCAO) approach, which directly included the Hubbard repulsion on the V sites, were applied to investigate the band structure of NaV₂O₅. More recently, Mazurenko *et al.*²⁷ combined DFT calculations with dynamical mean-field theory aiming at understanding the insulating behavior of this compound in the high-temperature phase. The tight-binding LMTO method was also applied to CaV₂O₅ to obtain the spin exchange and effective four-band tight-binding model parameters for this compound.²⁸ In addition, approaches based on quantum chemistry^{29–32} have been applied to NaV₂O₅. An interesting feature of the approaches used in Refs. 31 and 32 is that being based on the strong coupling of V and O(1) p_y orbitals, they attribute the phase transition to the ordering of the spin rather than the charge subsystem.

While the band structures of NaV₂O₅ and CaV₂O₅ are rather well understood on the first-principles basis, the analysis of their optical properties, lattice dynamics, electronphonon coupling, and Raman scattering still rely on various model assumptions. Having been well investigated experimentally, these properties require a detailed theoretical treatment which does not depend on such assumptions. Moreover, the outcome of DFT calculations is further used as realistic input parameters for model calculations such as diagonalization quantum Monte Carlo or exact techniques.33,34

As far as NaV₂O₅ is concerned, in this paper we concentrate on the high-temperature phase where V ions in the rungs are equivalent. This enables us to understand its main properties and provides a starting point for investigation of the low-temperature phase. Since in CaV₂O₅ no structural phase transition is observed, our treatment there holds at any temperature. The paper is organized as follows: In Sec. II, we describe the method of calculation and present the band structure for NaV₂O₅ and CaV₂O₅ and related results like the density of states and the charge density. We provide the calculated dielectric tensor components $\varepsilon_{ii}(\omega)$ (*i*=*x*,*y*,*z*) for these two compounds in Sec. III. Section IV includes theoretical phonon frequencies and eigenvectors, as well as electron-phonon and spin-phonon coupling parameters. The phonon-induced changes in the dielectric function and the corresponding phonon Raman spectra will be presented in Sec. V. Finally, a summary of the results and suggestions for further investigations are given in the Conclusions.

II. CALCULATIONS OF THE ELECTRONIC STRUCTURE

A. Computational methods

All band structure calculations are performed within DFT using the full-potential augmented plane waves+local orbitals³⁵ (FP-APW+lo) formalism implemented in the WIEN2K code.³⁶ Exchange and correlation terms are described within the generalized gradient approximation (GGA).³⁷ The atomic sphere radii are chosen as 1.6 a.u. for V, 1.4 a.u. for the O atoms and Na, and 1.5 a.u. for Ca. In both compounds, all atomic positions have been relaxed starting from the experimentally measured ones as given in Ref. 38 for CaV₂O₅ and Ref. 3 for NaV₂O₅. In NaV₂O₅, for example, the shifts of the ions due to the relaxation of the structure are up to approximately 0.015 Å [for O(1) and O(2) in the *z* direction] with an energy gain of roughly 30 meV per unit cell.

Comparing the two materials, they have slightly different lattice constants and ion coordinates. For example, since V is less positively charged in CaV2O5, the lengths of the V-O bonds are slightly larger than those in NaV₂O₅. Specifically, the optimized values for the V-O(3) and V-O(1) bond lengths are 1.62 (1.67) Å and 1.82 (1.85) Å in NaV_2O_5 (CaV₂O₅). At the same time, the spacing between Ca and the O(1) plane (2.39 Å) is smaller than the Na-O(1) plane distance in NaV_2O_5 (2.44 Å), since the bigger Ca ion exhibits a stronger Coulomb interaction with oxygen compared to Na. The geometry relaxation allows us to make the calculations not directly relying on the experimentally measured structural data and thereby leads to small quantitative differences compared to the NaV₂O₅ calculations performed by Smolinski et al.³ At the same time, this provides the energy scale related to unit cell distortions as it is realized, for example, in the lowtemperature phase.

We do not include correlational effects by using an LDA+U approach in our calculations, but we have estimated the Hubbard U for NaV_2O_5 and CaV_2O_5 from our data by the following procedure. Similarly to what is described in Ref. 3, we have added a small amount of electronic charge to the system and estimated U from the resulting change of the V bands. Charge neutrality was accounted for by two different procedures: When putting the positive charge on the Na sites, the resulting U was estimated to be 2.8 eV for NaV_2O_5 [averaged over the Brillouin zone (BZ)] in good agreement with Smolinski et al.³ We preferred, however, to provide the positive charge in terms of a uniform background, which leads to a U value of 2.45 eV for both compounds, demonstrating that U only weakly depends on the ion's surrounding. This procedure has the advantage that the band energy shifts are much more uniform with respect to different kpoints of the BZ than when the additional positive charge is located at the Na sites (differences of hundredths of an eV in



FIG. 2. Band structure and density of states (in states per unit cell and eV) of NaV₂O₅.

the former case compared to tenths of an eV in the latter case).

B. Band structure and density of states

The band structures and densities of states of NaV₂O₅ and CaV₂O₅ are shown in Figs. 2 and 3, respectively. Focusing on NaV₂O₅ first, the bands 3-4 eV below the Fermi level are due to O 2*p* states. Their smallest distance to the valence band minimum (at the Γ point) will be denoted as E_g later in



FIG. 3. Band structure and density of states (in states per unit cell and eV) of CaV₂O₅.

the text. The unoccupied states exhibit mainly V character with a small admixture of oxygen. The bands intersecting the Fermi level in the k_y direction are formed by the bonding combination of V orbitals. Their dispersion is due to hopping along the ladders while the splitting of this pair of bands at the Γ point is due to interladder hopping. The two bands just above the Fermi level originate from the antibonding combination of V d_{xy} states. The situation for CaV₂O₅ is similar, where some quantitative differences will be discussed below and in the context of its optical properties.

The bands can be mapped onto a tight-binding model with the one-ladder parameters t_{\parallel} of the in-rung hopping and t_{\parallel} representing the hopping along the ladder. The theoretically determined values for NaV₂O₅ are $t_{\perp} = 0.387$ eV and t_{\parallel} =0.175 eV, which are close to the data of Ref. 3. For CaV₂O₅, we obtained in the same way $t_{\perp} = 0.321$ eV and t_{\parallel} =0.143 eV, in agreement with the results of Korotin *et al.*²⁸ who applied the LDA+U technique in their calculations. Compared to their results, our hopping matrix elements are slightly increased, which is due to the changes in the interatomic distances as a result of the structural relaxation. We note that both t_{\parallel} and t_{\parallel} , are smaller for CaV₂O₅ than for NaV₂O₅. At the same time, the splitting of the *bonding* bands in the Γ point arising from the interladder hopping is much larger in CaV_2O_5 (0.49 eV) than in NaV_2O_5 (0.23 eV) since the distance between the ladders is smaller in the former. The corresponding interladder hopping matrix elements between the closest V atoms of neighboring ladders, t_i , are 0.13 and 0.24 eV for NaV₂O₅ and CaV₂O₅, respectively. When the lattice is deformed by a displacement of ions corresponding to a phonon mode, the tight-binding parameters as well as the on-site energies change. This kind of electron-phonon coupling will be discussed below.

The influence of the Hubbard term U on the properties of V-based ladder compounds is widely discussed in the literature. It is important to mention that the enhanced electron correlation when accounted for by the Hubbard parameter reproduces the semiconducting behavior with the charge gap close to $2|t_{\perp}|$.¹⁸ Correspondingly, the dispersion along the *y* axis of the band derived from the bonding combination of V d_{xy} orbitals will be π rather than 2π periodic.^{39,40} At the same time, we shall see below that the physical properties determined by the electron density are not strongly influenced by the Hubbard repulsion and can be described reliably within DFT.

To illustrate the charge density distribution within the unit cell, we exemplarily present the electron charge density for NaV_2O_5 in Fig. 4 in two perpendicular planes. The upper panel clearly shows the role of the unit cell asymmetry on the charge density arising due to the presence of the apical oxygen O(3). This asymmetry, on the one hand, leads to a strong Holstein-like electron-phonon coupling and, on the other hand, diminishes the overlap of the V orbitals with O(1) and O(2) states, thus decreasing the hopping matrix elements and correspondingly the components of the dielectric tensor. In addition, the lower panel shows the preferred orientation of the in-ladder oxygen states and a relatively small overlap of the orbitals from different ladders.



FIG. 4. Valence electron density of NaV₂O₅ in the (x,z) plane (upper panel) and the (x, y) plane (lower panel), which both contain the V positions. The logarithmic contour lines range from 0.07 $e/Å^3$ to 2.3 $e/Å^3$.

III. DIELECTRIC FUNCTION

Figures 5 and 6 present the real and imaginary parts of the diagonal dielectric tensor components, Re $\varepsilon_{ii}(\omega)$ and Im $\varepsilon_{ii}(\omega)$, in the experimentally measured range, where the Cartesian index *i* corresponds to the light polarization directions. Im $\varepsilon_{ii}(\omega)$ was calculated within the random phase approximation (RPA), based on the Kohn-Sham orbitals including a lifetime broadening of the optical interband transitions of 0.1 eV, while Re $\varepsilon_{ii}(\omega)$ is obtained by Kramers-Kronig transformation.



FIG. 5. Diagonal components of the dielectric function $\varepsilon_{ii}(\omega)$ of NaV₂O₅.



FIG. 6. Diagonal components of the dielectric function $\varepsilon_{ii}(\omega)$ of CaV₂O₅.

Let us first discuss the in-plane response of NaV₂O₅. The most interesting feature of the xx component (light polarized along the rungs) is a strong peak at 1.03 eV in agreement with experiment.^{16,41,42} An analysis of the interband momentum matrix elements at different electron wave vectors k_{v} shows that the first peak in the xx response arises due to transitions between the bonding and antibonding band states within one V rung. The energy of the peak is larger than $2t_{\perp}$ because of the band dispersion along the y axis and can be estimated to be $2(t_{\parallel} + t_{\parallel})$, which is 1.12 eV. Since the transitions between d_{xy} orbitals have very small matrix elements due to the large V-V distance, the admixture of O(1) p_v states in the antibonding state is responsible for a sizable intrarung transition matrix element. We mention here that this admixture provides some support to the arguments of Refs. 31 and 32. It rapidly decreases, however, with the increase of k_v due to the corresponding decrease of the oxygen contribution, which was first noticed in Ref. 3. For this reason the peak mostly originates from transitions in the vicinity of the Γ point.

The *yy* component (light polarized along the legs) is dominated by a double-peak structure at 1.27 eV and 1.78 eV, respectively. It is considerably weaker than the *xx* response. The analysis of the band structure reveals that the shoulder at 1.3 eV comes from in-rung transitions. These can contribute to $\varepsilon_{yy}(\omega)$ since at finite k_x values the in-rung states are neither odd nor even with respect to the $x \rightarrow -x$ transformation and, therefore, can couple to light polarized along the *y* axis. The broad maximum at $\omega = 1.8$ eV is related to transitions from the bonding V d_{xy} states to O(2) p_x states admixed to V- d_{xz} -derived orbitals at approximately 1.7 eV above the Fermi level.

In both polarizations, the peaks occurring at higher energies ($\omega > 3 \text{ eV}$) originate from transitions between O 2p and V orbitals. For example, the broad feature around 3 eV in the xx spectra arises from transitions between O(1) 2p_z states at -3.3 eV and bonding V d_{xy} states around E_F . Comparing to

TABLE I. Calculated frequencies and eigenvectors of the A_g phonon modes of NaV₂O₅ compared to experiment.

| Freq | uency (ci | Eigenvector | | | | | | | Assignment | | | |
|------------|-----------|-------------|-------|------------------|-------|----------|----------|----------|------------|----------|---------------------|----------------------------------|
| Experiment | | Theory | | | | | | | | | | |
| Ref. 11 | Ref. 44 | | V_x | \mathbf{V}_{z} | Naz | $O(1)_z$ | $O(2)_x$ | $O(2)_z$ | $O(3)_x$ | $O(3)_z$ | Refs. 44 and 46 | This work |
| 970 | 969 | 996 | 0.04 | 0.25 | -0.01 | 0.01 | 0.01 | -0.00 | -0.05 | -0.43 | V-O(3) stretching | V-O(3) stretching |
| 530 | 534 | 512 | 0.16 | -0.07 | 0.01 | 0.16 | 0.45 | 0.06 | -0.05 | -0.01 | V-O(2) stretching | V-O(2) stretching |
| 450 | 448 | 467 | 0.42 | -0.06 | 0.01 | 0.15 | -0.21 | -0.05 | -0.11 | 0.01 | V-O(1)-V bending | V-O(1)-V bending |
| 422 | 423 | 414 | -0.19 | -0.17 | 0.00 | 0.44 | -0.08 | -0.18 | 0.18 | -0.14 | O(3)-V-O(2) bending | $O(1)_z + O(3) - V - O(2)$ bend. |
| 304 | 304 | 308 | 0.02 | 0.19 | -0.04 | 0.18 | -0.07 | 0.39 | 0.19 | 0.09 | O(3)-V-O(2) bending | O(3)-V-O(2) bending |
| 230 | 233 | 232 | 0.17 | 0.06 | 0.03 | -0.13 | 0.06 | -0.16 | 0.42 | -0.00 | O(3)-V-O(2) bending | O(3)-V-O(2) bending |
| 178 | 179 | 176 | -0.02 | 0.28 | -0.40 | 0.10 | 0.04 | -0.22 | -0.06 | 0.18 | Na c | $Na \ c$ |
| 90 | 90 | 111 | -0.04 | 0.30 | 0.42 | 0.13 | 0.03 | -0.16 | -0.08 | 0.18 | chain rot. | chain rot. |

experiment, we want to point out that all theoretically obtained features reproduce the corresponding experimental findings very well.¹⁶

In CaV₂O₅, the character of the transitions is, in general, the same as in NaV_2O_5 . The fact that Ca provides one more valence electron to the system compared to Na has two obvious effects: First, the optical response is stronger compared to NaV₂O₅. Second, the peak present in NaV₂O₅ around 3 eV is missing, since the bonding V d_{xy} states are occupied and thus do not provide final states for the transitions. At the same time, since the in-ladder hopping matrix elements are smaller in CaV₂O₅ than in NaV₂O₅, the spectrum of unoccupied band states in CaV₂O₅ is denser, as can be seen in Figs. 2 and 3. For this reason, the low-energy part of the dielectric function ($\omega < 1 \text{ eV}$) of CaV₂O₅ shows a more complicated ω dependence than that for NaV₂O₅ since more interband transitions are allowed at this spectral range. A comparison with experiment for this compound which can also provide an experimental test of the applicability of the DFT for the description of optical properties of half-filled ladder compounds is not possible at present since to the best of our knowledge no measured data of the dielectric function of CaV_2O_5 single crystals are available.

IV. LATTICE DYNAMICS

A. Phonon modes

For the calculation of the A_g phonon modes we applied the *frozen-phonon* approximation. To this extent, the atomic positions have been moved from their equilibrium. Four displacements (two in positive and negative direction, respectively) for each degree of freedom have been taken into account. The resulting forces were used to obtain the energy hypersurface according to the procedure described in Ref. 43 and to set up the dynamical matrix. Since the harmonic fully symmetric ion vibrations do not change the occupancy of the V sites from single (of fractional) to double, the electron correlations do not significantly influence the elements of the dynamical matrix. At the same time, the correlation effects could be more important for the anharmonic terms relating the lattice forces and ion displacements.

The frequencies of the A_g modes for NaV₂O₅ and CaV₂O₅ are presented in Tables I and II, respectively, and compared to experimental data. The corresponding eigenvectors presented in these tables, $\mathbf{e}_{\alpha\zeta}$, are related to the real displacements $\mathbf{u}_{\ell}^{\alpha}$ by

| Frequency (cm ⁻¹) | | | | | Eigen | vector | | | | Assignment | | |
|-------------------------------|---------|--------|-------|------------------|-----------------|----------|----------|----------|----------|------------|---------------------|---------------------------------|
| Experiment | | Theory | | | | | | | | | | |
| Ref. 45 | Ref. 46 | | V_x | \mathbf{V}_{z} | Ca _z | $O(1)_z$ | $O(2)_x$ | $O(2)_z$ | $O(3)_x$ | $O(3)_z$ | Ref. 46 | This work |
| 935 | 932 | 900 | 0.06 | 0.24 | 0.01 | 0.02 | 0.02 | -0.02 | -0.08 | -0.42 | V-O(3) stretching | V-O(3) stretching |
| 542 | 539 | 516 | -0.01 | -0.05 | -0.01 | 0.11 | 0.49 | 0.07 | -0.02 | 0.00 | V-O(2) stretching | V-O(2) stretching |
| 472 | 470 | 446 | 0.36 | -0.16 | 0.00 | 0.39 | -0.09 | -0.05 | -0.08 | -0.00 | V-O(1)-V bending | V-O(1)-V bending |
| 421 | 422 | 412 | -0.34 | -0.12 | 0.02 | 0.27 | -0.05 | -0.17 | 0.18 | -0.13 | O(3)-V-O(2) bending | $O(1)_z + O(3)$ -V-O(2) bending |
| 337 | ? | 307 | 0.09 | 0.20 | 0.07 | 0.10 | -0.01 | 0.20 | 0.39 | 0.05 | O(3)-V-O(2) bending | O(3)-V-O(2) bending |
| 282 | 235.6 | 265 | 0.19 | -0.10 | -0.14 | -0.18 | 0.09 | -0.31 | 0.25 | -0.08 | O(3)-V-O(2) bending | O(3)-V-O(2) bending |
| 238 | 138.6 | 201 | 0.02 | 0.21 | 0.39 | 0.03 | 0.06 | -0.31 | -0.05 | 0.17 | Ca c | chain rot. |
| 91 | 90 | 106 | -0.05 | 0.32 | -0.39 | 0.15 | 0.01 | -0.15 | -0.06 | 0.19 | chain rot. | $Ca \ c$ |

TABLE II. Calculated frequencies and eigenvectors of the A_{g} phonon modes of CaV₂O₂ compared to experiment.

$$\mathbf{e}_{\alpha\zeta} = \operatorname{const} \times \mathbf{u}_{\zeta}^{\alpha} \sqrt{M_{\alpha}} \tag{1}$$

and are normalized as

$$\sum_{\alpha=1}^{N} \mathbf{e}_{\alpha\zeta}^{2} = 1, \qquad (2)$$

where α enumerates the ions with mass M_{α} , N=16 is the number of ions per unit cell, and ζ indicates the phonon mode. In order to visualize the lattice distortions according to the phonon eigenvectors, the corresponding atomic displacements of NaV₂O₅ are shown in Fig. 7, where the eigenvector components of Table I refer to the equivalent positions labeled in the figure. The phonon eigenvectors of CaV₂O₅ are very similar, up to some differences discussed later.

For the eigenfrequencies of the NaV₂O₅ A_g modes, good agreement with experiments^{11,44,47} is found, with deviations smaller than 5%. Only for the lowest-energy mode is the difference larger. In full agreement with the results of Refs. 11, 44, and 47 the eigenvector of the 996 cm⁻¹ mode represents a stretching between V and the apical oxygen. Also the V-O(2) stretching of the 512 cm⁻¹ mode and the V-O(1)-V bending of the 467 cm⁻¹ mode as suggested in Ref. 44 are verified, where we, however, find admixtures of an $O(1)_{\tau}$ motion for the former and an $O(2)_x$ movement for the latter, respectively. In the eigenvector of the 414 cm⁻¹ mode, the zdisplacement of the in-rung oxygen O(1) is dominating, while this mode is described as pure O(3)-V-O(2) bending in Ref. 46. At the same time, our theoretical frequencies are much closer to experiment (2% deviation) than the calculated frequencies in Ref. 46 (9% difference). For the 308 cm^{-1} , the 232 cm⁻¹, the 176 cm⁻¹, and the 111 cm⁻¹ modes, the agreement of our results with the assignment of Popovic et al.46 is good. However, in most of the modes we find a more pronounced involvement of O(1) compared to the interpretation of experimental results.

For the eigenfrequencies of the $CaV_2O_5 A_g$ modes, the agreement between theory and experiment⁴⁶ is very good for the modes above 400 cm⁻¹. For these vibrations, the experimental assignment with respect to their symmetry is unambiguous. The lower frequency of the apical oxygen vibration in CaV₂O₅ compared to NaV₂O₅ is due to larger interionic distances and, hence, smaller force constants. A change of 5% can be estimated within the Coulomb picture from the different vanadium charges in NaV₂O₅ and CaV₂O₅ (i.e., 4.5 and 4, respectively), which is in qualitative agreement with experiment.

The two lowest-frequency modes are swapped when Na is replaced by Ca; i.e., the in-phase motion of Ca with the other atoms of the ladder (chain rotation) has higher energy than the out-of-phase vibration, where Ca vibrates ||c| in a direction opposite to the ladder. The frequency of the chain rotation mode (201 cm⁻¹) is roughly twice as high as in NaV₂O₅, representing a difficulty in the interpretation of the measured modes of CaV₂O₅ which in Refs. 46 and 45 was done in comparison with the phonons of NaV₂O₅. In Ref. 46 the 138 cm⁻¹ mode of the unpolarized spectrum was interpreted as A_g vibration since its frequency compared to that of the (Na||c) mode scales as the inverse square root of the corre-



FIG. 7. Eigenvectors of NaV₂O₅.

sponding masses. From our analysis we conclude, that the measured 138 cm⁻¹ mode is not an A_g vibration. The physical origin of the frequency shift of the chain rotation mode is related to the stronger interladder interaction in CaV₂O₅ which is also reflected in the enhanced tight-binding parameter t_i (see Sec. IV B). On the other hand, the higher Ca mass is mainly responsible for the decrease of the "Ca $\|c$ " mode frequency. It is still unclear, however, whether the calculated 201 cm⁻¹ mode corresponds to the experimentally observed 213 cm⁻¹ vibration⁴⁶ or, more probable, to a mode at 235 cm⁻¹ (Ref. 46) (or 238 cm⁻¹ according to Ref. 45) which has been assigned as an A_g mode in both papers. In the latter case our calculated frequency of 265 cm⁻¹ can be related to the measured 282 cm⁻¹ vibration.⁴⁵ A similar problem concerns the interpretation of one more A_g mode somewhat above 300 cm⁻¹, where no clear experimental assignment is available in Ref. 46. In this context, the interpretation of the

| $\omega_{\rm th}~({\rm cm}^{-1})$ | $\delta t_{\parallel}/\delta Q~(\mathrm{eV})$ | $\delta t_{\perp} / \delta Q \; (\mathrm{eV})$ | $\delta t_i / \delta Q$ (eV) | $\delta E_g / \delta Q$ (eV) | $(\delta J/J)_{\parallel}/\delta Q$ | $(\delta J/J)_{\perp}/\delta Q$ | | | |
|---|---|--|------------------------------|------------------------------|-------------------------------------|---------------------------------|--|--|--|
| 996 | -0.0021 | -0.0099 | 0.0056 | -0.0936 | 0.0190 | 0.0449 | | | |
| 512 | -0.0210 | 0.0213 | -0.0439 | 0.0905 | 0.2952 | -0.0773 | | | |
| 467 | -0.0016 | -0.0115 | 0.0109 | -0.0037 | 0.0052 | 0.0478 | | | |
| 414 | -0.0110 | -0.0069 | -0.0142 | -0.0010 | 0.1284 | 0.0294 | | | |
| 308 | 0.0000 | -0.0167 | -0.0253 | 0.0554 | 0.0003 | 0.0967 | | | |
| 232 | -0.0012 | -0.0012 | 0.0257 | -0.0340 | 0.0085 | 0.0013 | | | |
| 176 | 0.0019 | 0.0061 | 0.0193 | -0.0185 | -0.0130 | -0.0225 | | | |
| 111 | 0.0008 | 0.0028 | 0.0132 | -0.0117 | -0.0055 | -0.0107 | | | |
| Undistorted: t_{\parallel} =0.175 eV, t_{\perp} =0.387 eV, t_i =0.117 eV, E_g =2.565 eV | | | | | | | | | |

TABLE III. Parameters of electron-phonon and spin-phonon coupling for the A_g eigenmodes of NaV₂O₅.

Raman scattering intensities could be helpful for an unambiguous assignment as will be discussed in the next section.

B. Electron-phonon and spin-phonon coupling

When ions are shifted from their equilibrium positions, the changes of the band structure are a measure for the electron-phonon interaction. Two types of coupling can be considered: The first one is the Holstein coupling, where the site energies change with the ion displacements, while the other one is due to changes of the hopping parameters. At the same time, the exchange path, which is formed by transitions between different sites, is also influenced by the phonons. This effect results in spin-phonon coupling. To investigate the type of the electron-phonon coupling and its strength for each mode, in Tables III and IV we display the changes of various model parameters with the corresponding ion displacements $\mathbf{u}_{\zeta}^{\alpha}$ (up to ~0.05 Å). These are the hopping parameters t_{\parallel} , t_{\perp} , and t_i , the charge transfer gap E_g , and the exchange parameters J_{\parallel} (along the ladders) and J_{\perp} (within the rungs). J_{\parallel} and J_{\perp} can be estimated as $\sim t_{\parallel}^2/E_g$ and $\sim t_{\perp}^2/E_g$, respectively.¹⁴ In this context we introduce the dimensionless phonon coordinate Q by the relation

$$Q \sqrt{\frac{\hbar}{M_{\alpha}\omega_{\zeta}}} \mathbf{e}_{\alpha\zeta} = \mathbf{u}_{\zeta}^{\alpha}.$$
 (3)

It turns out that only the higher-frequency phonons considerably modulate the one-ladder parameters t_{\perp} and t_{\parallel} . The changes of the hopping matrix elements corresponding to Q=1 are below 0.025 eV, while they can be much larger in the energy shifts δE_g . Therefore the main mechanism of electron-phonon coupling can be assigned to a Holstein-like interaction. Our results also allow us to estimate the strength of spin-phonon coupling arising due to the phonon-induced modulation of the exchange parameters. The corresponding relative changes are summarized in Tables III and IV.

The changes in the matrix elements can be understood as a result of the altered interionic distances and the electronic on-site energies. For example, the large phonon-induced decrease of t_{\parallel} in the 512 cm⁻¹ vibration of NaV₂O₅ is a consequence of the larger V-O distance in the same leg (see Fig. 7). At the same time, the V-O distance along the x axis changes from 0.274 Å to 0.309 Å at Q=1. The decrease of t_{\perp} for the 308 cm⁻¹ mode is due to an enhanced z-axis distance between V and the in-rung oxygen O(1) by 0.02 Å going from the relaxed to the distorted structure with Q=1. As a consequence, also the energy difference of the V and O(1) orbitals is increased, diminishing the hopping parameter t_{\perp} . The very strong modulation of the interladder hopping t_i by the 512 cm⁻¹ mode is due to a zigzaglike deformation of the legs in the (x, y) plane—i.e., a vibration of neighboring vanadium and oxygen atoms of one leg in the

TABLE IV. Parameters of electron-phonon and spin-phonon coupling for the A_g eigenmodes of CaV₂O₅.

| $\omega_{\rm th}~({\rm cm}^{-1})$ | $\delta t_{\parallel}/\delta Q~(\mathrm{eV})$ | $\delta t_{\perp} / \delta Q \; (\mathrm{eV})$ | $\delta t_i / \delta Q$ (eV) | $\delta E_g / \delta Q$ (eV) | $(\delta J/J)_{\parallel}/\delta Q$ | $(\delta J/J)_{\perp}/\delta Q$ | | | |
|---|---|--|------------------------------|------------------------------|-------------------------------------|---------------------------------|--|--|--|
| 900 | -0.0029 | -0.0089 | 0.0078 | -0.1286 | 0.0316 | 0.0470 | | | |
| 516 | -0.0113 | 0.0120 | -0.0253 | 0.0503 | 0.1863 | -0.0565 | | | |
| 446 | -0.0013 | -0.0232 | 0.0139 | -0.0228 | 0.0052 | 0.1399 | | | |
| 412 | 0.0056 | -0.0094 | 0.0223 | -0.0239 | -0.0815 | 0.0540 | | | |
| 307 | 0.0016 | -0.0017 | -0.0035 | 0.0054 | -0.0141 | 0.0185 | | | |
| 265 | 0.0071 | -0.0050 | -0.0337 | -0.0048 | -0.0895 | 0.0285 | | | |
| 201 | -0.0019 | 0.0035 | 0.0278 | -0.0080 | 0.0269 | -0.0217 | | | |
| 106 | 0.0013 | -0.0055 | -0.0110 | -0.0009 | -0.0227 | 0.0317 | | | |
| Undistorted: $t_{\parallel}=0.143$ eV. $t_{\perp}=0.321$ eV. $t_{i}=0.244$ eV. $E_{a}=2.882$ eV | | | | | | | | | |

opposite direction and hence an increase of this V-O₂ distance.

As can be seen in Tables III and IV, the biggest change for both t_{\parallel} and t_{\perp} , in NaV₂O₅ is caused by the V-O(2) stretching mode, while in CaV₂O₅ this mode leads to the most pronounced change only in t_{\parallel} , but the largest modulation of t_{\perp} is due to the V-O(1)-V mode (446 cm⁻¹). The reason for this can be found in the displacement of the inrung oxygen O(1) along the *z* axis, which is much larger compared to NaV₂O₅. For both compounds, the biggest effect on E_g is observed for the V-O(3) stretching mode.

We emphasize here that both electron-phonon coupling (leading to a modulation of E_g and the hopping matrix elements) and spin-phonon coupling (leading to a modulation of J_{\parallel}) in NaV₂O₅ and CaV₂O₅ are considerably strong.⁴⁸ For this reason the lattice distortion in the low-temperature phase of NaV₂O₅ can be related to total-energy changes originating from charge as well as spin^{31,32} degrees of freedom.

V. RAMAN SCATTERING

With the knowledge of the phonon modes and the dielectric functions we can calculate the phonon Raman spectra of NaV₂O₅ and CaV₂O₅. For this purpose we use the approach developed in Ref. 43, where at a given exciting light frequency ω_I the total Raman intensity I_R at temperature T in arbitrary units is

$$I_{R}(\omega_{R}) = \sum_{\zeta} \left[n_{B}(\omega_{\zeta}) + 1 \right] \left| \left\langle 1 \left| \frac{\partial \varepsilon_{ii}^{\omega_{I}}}{\partial Q} \hat{Q} \right| 0 \right\rangle \right|^{2} L(\omega_{R}, \omega_{\zeta}, \Gamma).$$

$$\tag{4}$$

Here ω_R is the Raman shift, and the Cartesian indices *ii* correspond to the polarizations of incident and scattered light, which are the same due to the orthorhombic symmetry of the crystal. $|1\rangle$ and $|0\rangle$ denote the one-phonon and phononless states, respectively, and \hat{Q} is the operator of the phonon coordinate. $n_B(\omega_{\zeta})=1/[\exp(\hbar\omega_{\zeta}/T)-1]$ is the phonon Bose distribution function, and $L(\omega_R, \omega_{\zeta}, \Gamma)$ is the Lorentzian shape of the phonon line with a broadening Γ , which was chosen to be 25 cm⁻¹ for all modes.

The total Raman intensity-i.e., the sum over all phonon contributions—is presented in Figs. 8 and 9 for NaV₂O₅ and CaV₂O₅, respectively, for an incident light energy of 2.41 eV $(\lambda = 514.5 \text{ nm})$, which is used in the Raman experiments available in the literature. In the xx polarization seven out of eight modes are clearly visible; only the 232 cm⁻¹ vibration has negligible intensity, in excellent agreement with experiments.^{11,44} We note that also the relative peak heights are fully reproduced. This scattering geometry exhibits the highest intensity for all modes except the highest one, which dominates the zz-polarized spectra. The intensity of all other modes in this polarization is two orders of magnitude smaller and hence hardly visible in the measured spectra. The only exception is the 110 cm⁻¹ mode, where theory cannot reproduce the experimentally observed sharp peak. One possible explanation could be provided by the extremely pronounced resonance behavior of most of the vibrations as will be dis-



FIG. 8. Raman intensity I_R for NaV₂O₅ in three different geometries at ω =2.41 eV (λ =514.5 nm) and T=300 K.

cussed below. The *yy* polarization exhibits intensities in between the magnitudes of the *xx* and *zz* counterparts. In accordance with experiment the 467 cm⁻¹ vibration is absent in this scattering geometry.

For CaV_2O_5 the situation is similar. The highest-energy mode exhibits the highest intensity in *zz* polarization. Between 400 and 600 cm⁻¹ the *xx* intensities are dominating. Only below 400 cm⁻¹, are the *yy* spectra comparable in magnitude or even bigger.

The Raman scattering intensity is governed by the change of the crystal polarizability with the nuclei vibrating around their equilibrium positions. The dependence of the dielectric



FIG. 9. Raman intensity I_R for CaV₂O₅ in three different geometries at ω =2.41 eV (λ =514.5 nm) and T=300 K.



FIG. 10. Derivatives of the dielectric functions $|\partial \varepsilon / \partial Q|^2$ with respect to displacements along the eigenvectors of the phonon modes of NaV₂O₅ as indicated by their phonon frequencies. The *zz* component is considerable only for the highest frequency and is therefore omitted in the other panels.

function on the phonon coordinate arises due to two main reasons—i.e., the Q dependence of the momentum matrix element and the Q dependence of the interband transition energy.⁴⁹ The latter contribution leads to a stronger resonance behavior of the Raman intensity than the former. To illustrate the influence of the lattice vibrations on the dielectric function, in Fig. 10 we present $|\partial \varepsilon_{ii}(\omega)/\partial Q|^2$ for the phonon modes of NaV₂O₅. In the energy range $\omega > 2.5$ eV the derivative of the xx component dominates over $|\partial \varepsilon_{vv}(\omega)/\partial Q|^2$ for all modes. In the low-energy region the latter shows a dramatic resonance behavior for the 232 cm⁻¹ and 308 cm⁻¹ vibrations, and is comparable or even slightly larger in magnitude than $\left|\partial \varepsilon_{xx}(\omega)/\partial Q\right|^2$ around 2 eV for the next three modes higher in energy. All modes but the highest one exhibit extremely strong resonances in the infrared in either of the two polarizations. For the highest mode, the zz polarization is dominating, while only below 2 eV the yy component becomes more pronounced. We thus predict much higher Raman scattering intensities for incident light frequencies both higher and lower than those used in experiments so far. We mention in this context that Fischer *et al.*¹¹ observed strong relative intensity changes in xx geometry when measuring the low-temperature phase using different photon energies.

A similarly strong resonance behaviour is also expected for CaV_2O_5 . While with the exception of the highest mode the intensities of the zz component are small and the influence of the photon energy is negligible in NaV₂O₅, this scattering geometry is slightly richer for CaV₂O₅, with generally slightly higher relative intensities and an even more pronounced resonant behavior of the highest mode.

VI. CONCLUSIONS

In this paper, we have studied optical properties and lattice dynamics of NaV₂O₅ and CaV₂O₅ in the Pmmn phase from first principles. The calculations are based on the theoretically optimized crystal structures obtained within the generalized gradient approximation. Effective band structure parameters have been extracted by mapping our results onto a tight-binding model. We have obtained the Hubbard repulsion U on the V sites being approximately 2.45 eV, both for NaV_2O_5 and CaV_2O_5 . The dielectric functions have been determined within the random phase approximation and are in very good agreement with available experiments. Our results show that the 1 eV peak in the xx component arises due to transitions between the bonding and antibonding combination of V d_{xy} orbitals within one rung. By diagonalizing the dynamical matrix we have obtained the phonon frequencies for the fully symmetric vibrations which are in very good agreement with measured data. With the knowledge of the phonon eigenvectors and the changes of the band structure caused by the phonon modes we have estimated the parameters of electron-phonon and spin-phonon coupling for both compounds. We find that the strongest contribution to the electron-phonon coupling comes from the phonon modulation of the charge transfer gap E_g . At the same time, other effects arising from altered hopping matrix elements can be important. Finally, we have calculated the phonon Raman spectra of these compounds and analyzed the frequencydependent dielectric function modulated by the ion displacements according to the lattice vibrations. On this basis we predict a strong resonance behavior for both NaV₂O₅ and CaV₂O₅.

As an outlook for further investigations, this detailed analysis provides a basis for comparison with the low-temperature phase. Moreover, the Hubbard parameters extracted in this work can be used as input for further calculations by, e.g., exact diagonalization^{33,50} or quantum Monte Carlo simulations.³⁴

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